

Surface Mount Switching Diode

Features:

- *Low Current Leakage
- *Low Forward Voltage
- *Reverse Recover Time $T_{rr} \leq 4\text{ns}$
- *Small Outline Surface Mount SOT-23 Package

SWITCHING DIODE
100-200m AMPERRES
75-100 VOLTS

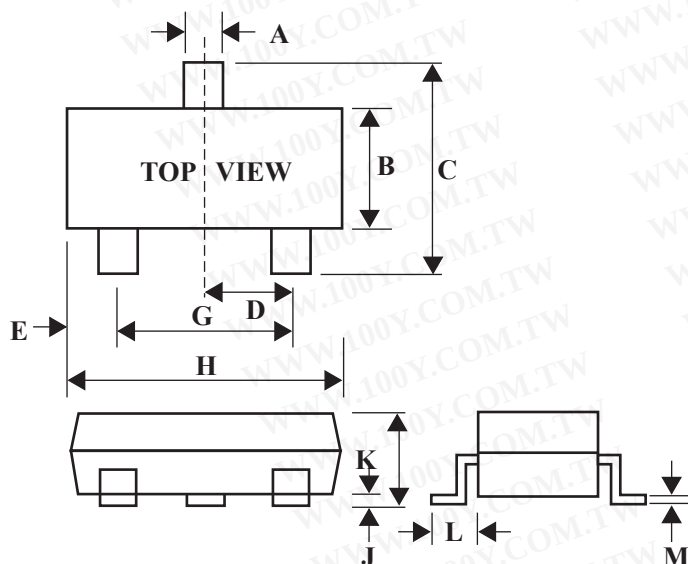


SOT-23

勝特力材料 886-3-5753170
勝特力电子(上海) 86-21-54151736
勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

SOT-23 Outline Dimensions

Unit:mm



Dim	Min	Max
A	0.35	0.51
B	1.19	1.40
C	2.10	3.00
D	0.85	1.05
E	0.46	1.00
G	1.70	2.10
H	2.70	3.10
J	0.01	0.13
K	0.89	1.10
L	0.30	0.61
M	0.076	0.25

**MMBD2836 / MMBD2838
MMBD7000**



Maximum Ratings (EACH DIODE)

Characteristic	Symbol	MMBD2836	MMBD2838	MMBD7000	Unit
Reverse Voltage	V_R	75		100	Volts
Forward Current	I_F	100		200	mAdc
Peak Forward Surge Current	I_{FM}	500			mAdc

Thermal Characteristics

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board *1, $T_A=25^\circ\text{C}$ Derate Above 25°C	P_D	225 1.8	mW mW/ $^\circ\text{C}$
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C/W}$
Total Device Dissipation Alumina Substrate*2 $T_A=25^\circ\text{C}$ Derate Above 25°C	P_D	300 2.4	mW mW/ $^\circ\text{C}$
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C/W}$
Junction and Storage Temperature	T_J, T_{stg}	-55 to + 150	$^\circ\text{C}$

*1 ER-5=1.0x0.75x0.062 in

*2 Alumina=0.4x0.3x0.024 in 99.5% Alumina

Electrical Characteristics ($T_A=25^\circ\text{C}$ Unless Otherwise Note) (Each Diode)

Characteristic	Symbol	Min	Max	Unit
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Off Characteristics

Reverse Breakdown Voltage($I_{BR}=100\mu\text{Adc}$) MMBD2836/MMBD2838 MMBD7000	V_{BR}	75 100	-	Vdc
Reverse Voltage Leakage Current $V_R=50\text{V}$ MMBD2836/MMBD2838 MMBD7000	I_R	-	0.1 1.0	μAdc
$V_R=100\text{V}$ MMBD7000			3.0	
$V_R=50\text{V}, T_J=125^\circ\text{C}$ MMBD7000			100	

**MMBD2836 / MMBD2838
MMBD7000**



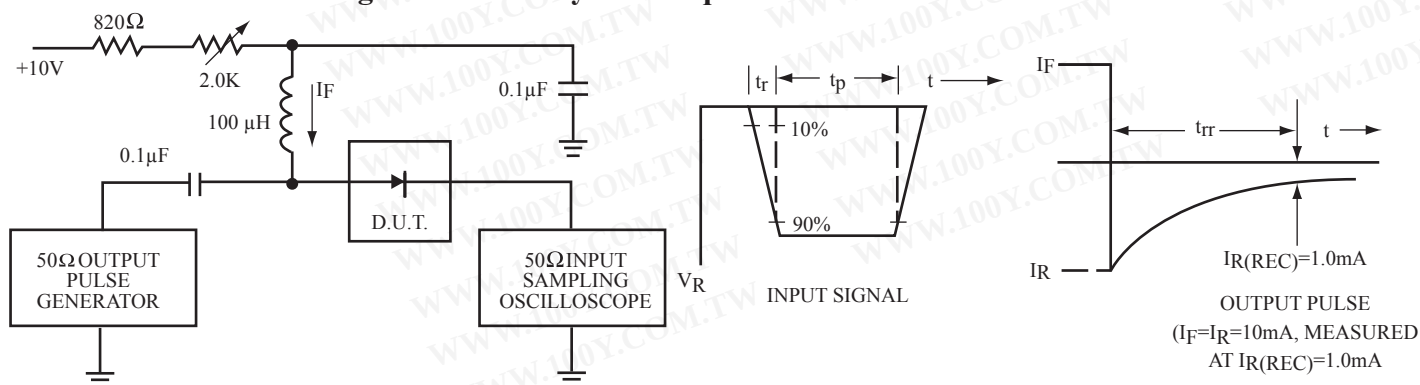
Off Characteristic

Characteristic	Symbol	Min	Max	Unit
Diode Capacitance MMBD2836/MMBD2838 ($V_R=0$, $f=1.0\text{MHz}$) MMBD7000	C_D		4.0 1.5	PF
Forward Voltage ($I_F=1.0\text{mA}$) MMBD7000 ($I_F=10\text{mA}$) MMBD2836/MMBD2838 MMBD7000 ($I_F=50\text{mA}$) MMBD2836/MMBD2838 ($I_F=100\text{mA}$) MMBD2836/MMBD2838 MMBD7000	V_F		700 1000 820 1000 1200 1100	mVdc
Reverse Recovery Time (Figure 1.) $I_F=I_R=10\text{mA}$, $V_R=5.0\text{Vdc}$ $I_R(\text{REC})=1.0\text{mA}$, $R_L=100$	t_{rr}		4.0	nS

Device Marking

Item	Marking	Equivalent Circuit diagram
MMBD2838	A6	
MMBD2836	A2	
MMBD7000	M5C	

Figure 1. Recovery Time Equivalent Test Circuit



- Notes: 1. A 2.0 kΩ variable resistor for a Forward Current (I_F) of 10 mA
 2. Input pulses is adjusted so $I_R(\text{peak})$ is equal to 10 mA
 3. $t_p \gg t_{rr}$

MMBD2836 / MMBD2838
 MMBD7000

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FIGURE 2. FORWARD VOLTAGE

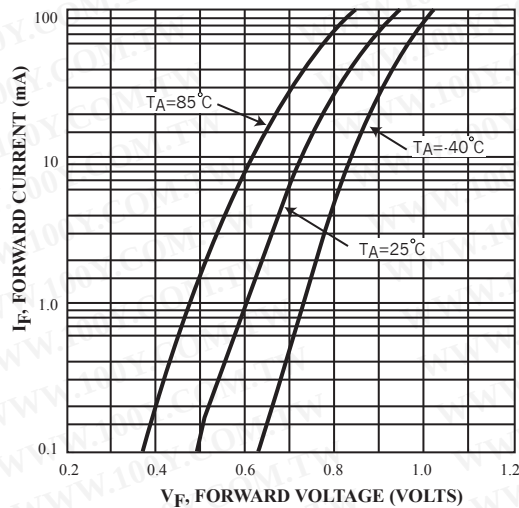


FIGURE 3. LEAKAGE CURRENT

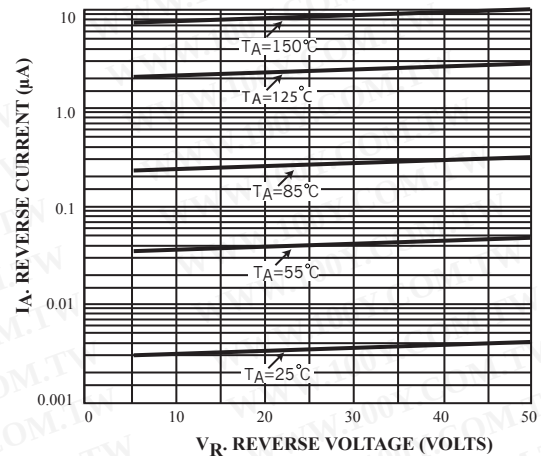


FIGURE 4. CAPACITANCE(2836)

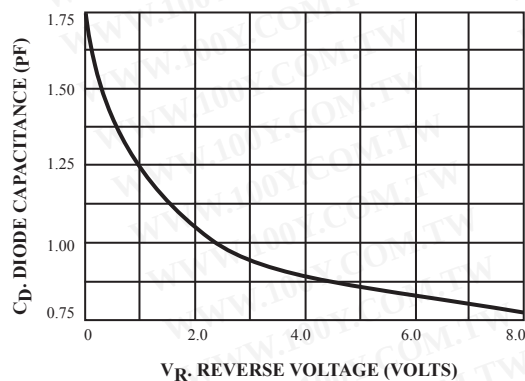


FIGURE 5. CAPACITANCE(2838)

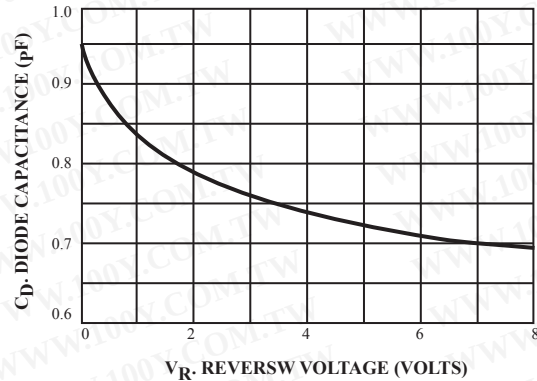


FIGURE 6. CAPACITANCE(7000)

